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Datasheet of TS5A3159QDBVRQ1 - IC ANLG SW SPDT SOT23-6

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TS5A3159-Q1 1-Ω SPDT Analog Switch

1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
 - Device Temperature Grade 1: –40°C to 125°C Ambient Operating Temperature Range
 - Device HBM ESD Classification Level 2
 - Device CDM ESD Classification Level C4B
- Specified Break-Before-Make Switching
- Low ON-State Resistance (1 Ω)
- Control Inputs are 5-V Tolerant
- Low Charge Injection
- Excellent ON-Resistance Matching
- Low Total Harmonic Distortion
- 1.65-V to 5.5-V Single-Supply Operation

2 Applications

- Automotive Infotainment and Cluster
- Body Electronics and Lighting

3 Description

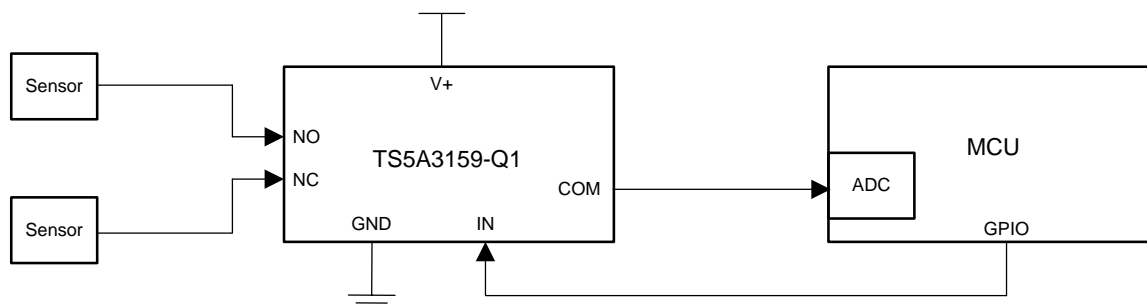
The TS5A3159-Q1 is a single-pole double-throw (SPDT) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and an excellent ON-resistance, matching with the break-before-make feature to prevent signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|------------|-------------------|
| TS5A3159-Q1 | SOT-23 (6) | 2.90 mm x 4.00 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Selector Application



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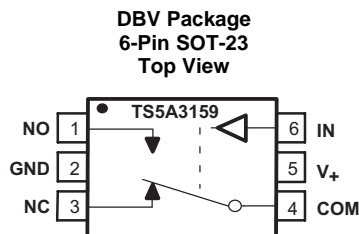
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision A (December 2012) to Revision B | Page |
|---|-------------|
| • Added ESD Ratings table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section | 3 |

| Changes from Original (November, 2012) to Revision A | Page |
|--|-------------|
| • Device going from Preview to Production | 1 |
| • Changed r_{on} max values from 1.1 to 1.3 | 4 |
| • Changed $I_{NC(OFF)}$, $I_{NO(OFF)}$ min and max values for 25°C from –2 and 2 to –6 and 6, respectively. Changed min and max values for Full from –20 and 20 to –150 and 150, respectively | 4 |
| • Changed $I_{NC(ON)}$, $I_{NO(ON)}$ min and max values for 25°C from –4 and 4 to –6 and 6, respectively. Changed min and max values for Full from –40 and 40 to –150 and 150, respectively | 4 |
| • Changed $I_{COM(ON)}$ min and max values for 25°C from –4 and 4 to –8 and 8, respectively. Changed min and max values for Full from –40 and 40 to –150 and 150, respectively. | 4 |
| • Inserted 25°C above Full in T_A column and inserted 0.5 μA max value for I_+ | 5 |
| • Changed max values for r_{peak} from 2.1 to 2.2 | 5 |
| • Changed max values for r_{on} from 1.5 to 1.8. | 5 |
| • Added 25°C to T_A column and added 0.5 max value to I_+ | 6 |
| • Changed r_{peak} max values from 2.7 to 2.9 | 7 |
| • Changed r_{on} max values from 2 to 2.3. | 7 |
| • Added 25°C to T_A column and added 0.5 max value to I_+ | 7 |
| • Changed r_{peak} max values from 4.9 to 5.2 | 8 |
| • Changed r_{on} max values from 3.2 to 3.5. | 8 |
| • Added 25°C to T_A column and added 0.5 max value to I_+ | 8 |
| • Changed ON-state resistance from 1.1 to 1.3 Ω | 16 |
| • Changed leakage current from ± 20 nA to ± 6 nA | 16 |

5 Pin Configuration and Functions



Pin Functions

| PIN | | I/O | DESCRIPTION |
|-----|----------------|-----|---|
| NO. | NAME | | |
| 1 | NO | I/O | Normally-open terminal |
| 2 | GND | — | Digital ground |
| 3 | NC | I/O | Normally-closed terminal |
| 4 | COM | I/O | Common terminal |
| 5 | V ₊ | I | Power supply |
| 6 | IN | I | Digital control pin to connect COM terminal to NO or NC terminals |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

| | | MIN | MAX | UNIT |
|------------------------------------|--|---|----------------------|------------|
| V ₊ | Supply voltage range ⁽²⁾ | -0.5 | 6.5 | V |
| V _{NO} , V _{COM} | Analog voltage range ⁽²⁾⁽³⁾⁽⁴⁾ | -0.5 | V ₊ + 0.5 | V |
| I _I / OK | Analog port diode current | V _{NO} , V _{COM} < 0 or V _{NO} , V _{COM} > V ₊ | | ±50 mA |
| I _{NO} , I _{COM} | ON-state switch current | V _{NO} , V _{COM} = 0 to V ₊ | | ±200 mA |
| | ON-state peak switch current ⁽⁵⁾ | | | ±400 mA |
| V _{IN} | Digital input voltage range ⁽²⁾⁽³⁾ | -0.5 | 6.5 | V |
| I _{IK} | Digital input clamp current | V _{IN} < 0 | | -50 mA |
| | Continuous current through V ₊ or GND | | | ±100 mA |
| T _{stg} | Storage temperature range | -65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4) This value is limited to 5.5 V maximum.
- (5) Pulse at 1 ms duration < 10% duty cycle.

6.2 ESD Ratings

| | | VALUE | UNIT | |
|--------------------|-------------------------|---|-----------------------------------|------|
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 ⁽¹⁾ | ±2000 | |
| | | Charged device model (CDM), per AEC Q100-011 | Corner pins (NO, NC, IN, and COM) | ±750 |
| | | | Other pins | ±500 |

- (1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

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6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | MIN | NOM | MAX | UNIT |
|-------------|-----|-----|-----|------|
| V+ | 1.8 | | 5 | V |
| IN | 0 | | 5 | V |
| NO, NC, COM | 0 | | 5 | V |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | TS5A3159-Q1 | UNIT |
|-------------------------------|--|--------------|------|
| | | DBV (SOT-23) | |
| | | 6 PINS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 192.9 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 133.3 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 37.6 | °C/W |
| ψ _{JT} | Junction-to-top characterization parameter | 38.9 | °C/W |
| ψ _{JB} | Junction-to-board characterization parameter | 37.1 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics for 5-V Supply

V₊ = 4.5 V to 5.5 V and T_A = -40°C to 125°C (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T _A | V ₊ | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|--|--|---|---|-------|--------------------|----------------|------|
| ANALOG SWITCH | | | | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | 0 | | V ₊ | V |
| r _{peak} | Peak ON resistance | 0 ≤ V _{NO} or V _{NC} ≤ V ₊ , I _{COM} = -30 mA | Switch ON, See Figure 11 | 25°C | 4.5 V | 1 1.5 | Ω |
| r _{on} | ON-state resistance | V _{NO} or V _{NC} = 2.5 V, I _{COM} = -30 mA | Switch ON, See Figure 10 | 25°C | 4.5 V | 0.75 1.3 | Ω |
| Δr _{on} | ON-state resistance match between channels | V _{NO} or V _{NC} = 2.5 V, I _{COM} = -30 mA | Switch ON, See Figure 10 | 25°C | 4.5 V | 0.1 | Ω |
| r _{on(flat)} | ON-state resistance flatness | 0 ≤ V _{NO} or V _{NC} ≤ V ₊ , I _{COM} = -30 mA | Switch ON, See Figure 10 | 25°C | 4.5 V | 0.233 | Ω |
| | | V _{NO} or V _{NC} = 1 V, 1.5 V, 2.5 V, I _{COM} = -30 mA | | 25°C | 4.5 V | 0.15 | Ω |
| I _{NC(OFF)} , I _{NO(OFF)} | NC, NO OFF leakage current | V _{NC} or V _{NO} = 4.5 V, V _{COM} = 0 | Switch OFF, See Figure 12 | 25°C | 5.5 V | -6 0.2 6 | nA |
| | | | | Full | 5.5 V | -150 150 | nA |
| I _{NC(ON)} , I _{NO(ON)} | NC, NO ON leakage current | V _{NC} or V _{NO} = 4.5 V, V _{COM} = Open | Switch ON, See Figure 13 | 25°C | 5.5 V | -6 2.8 6 | nA |
| | | | | Full | 5.5 V | -150 150 | nA |
| I _{COM(ON)} | COM ON leakage current | V _{NC} or V _{NO} = 4.5 V or Open, V _{COM} = 4.5 V | Switch ON, See Figure 13 | 25°C | 5.5 V | -8 0.47 8 | nA |
| | | | | Full | 5.5 V | -150 150 | nA |
| DIGITAL INPUTS (IN) | | | | | | | |
| V _{IH} | Input logic high | | Full | | 2.4 | 5.5 | V |
| V _{IL} | Input logic low | | Full | | 0 | 0.8 | V |
| I _{IH} , I _{IL} | Input leakage current | V _{IN} = 5.5 V or 0 | Full | 5.5 V | -1 | 1 | μA |

(1) T_A = 25°C

Electrical Characteristics for 5-V Supply (continued)

$V_+ = 4.5\text{ V to }5.5\text{ V}$ and $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|----------------------------------|---------------------------|---|---|-------|-------------------|-------|--------------------|------|---------------|
| DYNAMIC | | | | | | | | | |
| t_{ON} | Turn-on time | $V_{COM} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, See Figure 15 | 25°C | 4.5 V to 5.5 V | 20 | 35 | 40 | ns |
| t_{OFF} | Turn-off time | $V_{COM} = V_+$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, See Figure 15 | 25°C | 4.5 V to 5.5 V | 15 | 20 | 35 | ns |
| t_{BBM} | Break-before-make time | $V_{NC} = V_{NO} = V_+ / 2$, $R_L = 50\ \Omega$, | $C_L = 35\text{ pF}$, See Figure 16 | 25°C | 4.5 V to 5.5 V | 1 | 12 | 14.5 | ns |
| Q_C | Charge injection | $C_L = 1\text{ nF}$, $V_{GEN} = 0\text{ V}$, | See Figure 19 | 25°C | 5 V | 36 | | | pC |
| $C_{NC(OFF)}$, $C_{NO(OFF)}$ | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_+$ or GND, Switch OFF, | See Figure 13 | 25°C | 5 V | 23 | | | pF |
| $C_{NC(ON)}$, $C_{NO(ON)}$ | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_+$ or GND, Switch ON, | See Figure 13 | 25°C | 5 V | 84 | | | pF |
| $C_{COM(ON)}$ | COM ON capacitance | $V_{COM} = V_+$ or GND, Switch ON, | See Figure 13 | 25°C | 5 V | 84 | | | pF |
| C_{IN} | Digital input capacitance | $V_{IN} = V_+$ or GND, | See Figure 13 | 25°C | 5 V | 2.1 | | | pF |
| BW | Bandwidth | $R_L = 50\ \Omega$, Switch ON, | See Figure 16 | 25°C | 5 V | 100 | | | MHz |
| O_{ISO} | OFF isolation | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$, | Switch OFF, See Figure 17 | 25°C | 5 V | -65 | | | dB |
| X_{TALK} | Crosstalk | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$, | Switch ON, See Figure 18 | 25°C | 5 V | -65 | | | dB |
| THD | Total harmonic distortion | $R_L = 600\ \Omega$, $C_L = 50\text{ pF}$, | $f = 600\text{ Hz to }20\text{ kHz}$, See Figure 19 | 25°C | 5 V | 0.01% | | | |
| SUPPLY | | | | | | | | | |
| I_+ | Positive supply current | $V_{IN} = V_+$ or GND, | Switch ON or OFF | 25°C | 5.5 V | | | 0.1 | μA |
| | | | | Full | | | | 0.5 | |

6.6 Electrical Characteristics for 3.3-V Supply

$V_+ = 3\text{ V to }3.6\text{ V}$ and $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|------------------------------------|---|--|------------------------------|-------|-------|-------|--------------------|-------|----------|
| ANALOG SWITCH | | | | | | | | | |
| V_{COM} , V_{NO} , V_{NC} | Analog signal range | | | | | 0 | | V_+ | V |
| r_{peak} | Peak ON-state resistance | $0 \leq V_{NO}$ or $V_{NC} \leq V_+$, $I_{COM} = -24\text{ mA}$, | Switch ON, See Figure 10 | 25°C | 3 V | 1.35 | 2.2 | 2.2 | Ω |
| r_{on} | ON-state resistance | V_{NO} or $V_{NC} = 2\text{ V}$, $I_{COM} = -24\text{ mA}$, | Switch ON, See Figure 10 | 25°C | 3 V | 1.15 | 1.8 | 1.8 | Ω |
| Δr_{on} | ON-state resistance match between channels | V_{NO} or $V_{NC} = 2\text{ V}$, 0.8 V , $I_{COM} = -24\text{ mA}$, | Switch ON, See Figure 10 | 25°C | 3 V | 0.11 | | | Ω |
| $r_{on(Flat)}$ | ON-state resistance flatness | $0 \leq V_{NO}$ or $V_{NC} \leq V_+$, $I_{COM} = -24\text{ mA}$, V_{NO} or $V_{NC} = 2\text{ V}$, 0.8 V , $I_{COM} = -24\text{ mA}$, | Switch ON, See Figure 10 | 25°C | 3 V | 0.225 | | | Ω |
| $I_{NC(OFF)}$, $I_{NO(OFF)}$ | NC, NO OFF leakage current | V_{NC} or $V_{NO} = 3\text{ V}$, $V_{COM} = 0$, | Switch OFF, See Figure 11 | 25°C | 3.6 V | 0.2 | | | nA |
| $I_{NC(ON)}$, $I_{NO(ON)}$ | NC, NO ON leakage current | V_{NC} or $V_{NO} = 3\text{ V}$, $V_{COM} = \text{Open}$, | Switch ON, See Figure 12 | 25°C | 3.6 V | 2.8 | | | nA |
| $I_{COM(ON)}$ | COM ON leakage current | V_{NC} or $V_{NO} = 3\text{ V}$ or Open, $V_{COM} = 3\text{ V}$, | Switch ON, See Figure 12 | 25°C | 3.6 V | 0.47 | | | nA |

(1) $T_A = 25^\circ\text{C}$

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Electrical Characteristics for 3.3-V Supply (continued)
 $V_+ = 3\text{ V to }3.6\text{ V}$ and $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | T_A | V_+ | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|----------------------------|---------------------------|---|---|--------------|-----------------|-----|--------------------|------------|---------------|
| DIGITAL INPUTS (IN) | | | | | | | | | |
| V_{IH} | Input logic high | | | Full | | 2 | | 5.5 | V |
| V_{IL} | Input logic low | | | Full | | 0 | 0.6 | | V |
| I_{IH}, I_{IL} | Input leakage current | $V_{IN} = 5.5\text{ V or }0$ | | Full | 3.6 V | -1 | | 1 | μA |
| DYNAMIC | | | | | | | | | |
| t_{ON} | Turn-on time | $V_{COM} = V_+$, $R_L = 50\ \Omega$ | $C_L = 35\text{ pF}$, See Figure 15 | 25°C Full | 3 V to 3.6 V | | 30 | 40 55 | ns |
| t_{OFF} | Turn-off time | $V_{COM} = V_+$, $R_L = 50\ \Omega$ | $C_L = 35\text{ pF}$, See Figure 15 | 25°C Full | 3 V to 3.6 V | | 20 | 25 40 | ns |
| t_{BBM} | Break-before-make time | $V_{NC} = V_{NO} = V_+ / 2$, $R_L = 50\ \Omega$ | $C_L = 35\text{ pF}$, See Figure 16 | 25°C Full | 3 V to 3.6 V | | 1 | 21 29 | ns |
| Q_C | Charge injection | $C_L = 1\text{ nF}$, $V_{GEN} = 0\text{ V}$ | See Figure 19 | 25°C | 3.3 V | | | 20 | pC |
| $C_{NC(OFF)}, C_{NO(OFF)}$ | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_+$ or GND, Switch OFF | See Figure 13 | 25°C | 3.3 V | | | 23 | pF |
| $C_{NC(ON)}, C_{NO(ON)}$ | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_+$ or GND, Switch ON | See Figure 13 | 25°C | 3.3 V | | | 84 | pF |
| $C_{COM(ON)}$ | COM ON capacitance | $V_{COM} = V_+$ or GND, Switch ON | See Figure 13 | 25°C | 3.3 V | | | 84 | pF |
| C_{IN} | Digital input capacitance | $V_{IN} = V_+$ or GND | See Figure 13 | 25°C | 3.3 V | | | 2.1 | pF |
| BW | Bandwidth | $R_L = 50\ \Omega$, Switch ON | See Figure 16 | 25°C | 3.3 V | | | 100 | MHz |
| O_{ISO} | OFF isolation | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$ | Switch OFF, See Figure 17 | 25°C | 3.3 V | | | -65 | dB |
| X_{TALK} | Crosstalk | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$ | Switch ON, See Figure 18 | 25°C | 3.3 V | | | -65 | dB |
| THD | Total harmonic distortion | $R_L = 600\ \Omega$, $C_L = 50\text{ pF}$ | $f = 600\text{ Hz to }20\text{ kHz}$, See Figure 19 | 25°C | 3.3 V | | | 0.015% | |
| SUPPLY | | | | | | | | | |
| I_+ | Positive supply current | $V_{IN} = V_+$ or GND | Switch ON or OFF | 25°C Full | 3.6 V | | | 0.1 0.5 | μA |

6.7 Electrical Characteristics For 2.5-V Supply

$V_+ = 2.3 \text{ V to } 2.7 \text{ V}$ and $T_A = -40^\circ\text{C to } 125^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A | V_+ | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---|---|--|--------------|-------------------|--------------------|------------|---------------|
| ANALOG SWITCH | | | | | | | |
| V_{COM}, V_{NO}, V_{NC} Analog signal range | | | | 0 | | V_+ | V |
| r_{peak} Peak ON-state resistance | $0 \leq V_{NO} \text{ or } V_{NC} \leq V_+$, $I_{COM} = -8 \text{ mA}$ | Switch ON, See Figure 10 | 25°C Full | 2.5 V | 1.7 | 2.9 | Ω |
| r_{on} ON-state resistance | $V_{NO} \text{ or } V_{NC} = 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$ | Switch ON, See Figure 10 | 25°C Full | 2.5 V | 1.45 | 2.3 | Ω |
| Δr_{on} ON-state resistance match between channels | $V_{NO} \text{ or } V_{NC} = 0.8 \text{ V}, 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$ | Switch ON, See Figure 10 | 25°C | 2.5 V | 0.7 | | Ω |
| $r_{on(Flat)}$ ON-state resistance flatness | $0 \leq V_{NO} \text{ or } V_{NC} \leq V_+$, $I_{COM} = -8 \text{ mA}$ $V_{NO} \text{ or } V_{NC} = 0.8 \text{ V}, 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$ | Switch ON, See Figure 10 | 25°C 25°C | 2.5 V | 0.5 0.45 | | Ω |
| $I_{NC(OFF)}, I_{NO(OFF)}$ NC, NO Off leakage current | $V_{NC} \text{ or } V_{NO} = 2.3 \text{ V}$, $V_{COM} = 0$ | Switch OFF, See Figure 11 | 25°C | 2.7 V | 0.2 | | nA |
| $I_{NC(ON)}, I_{NO(ON)}$ NC, NO On leakage current | $V_{NC} \text{ or } V_{NO} = 2.3 \text{ V}$, $V_{COM} = \text{Open}$ | Switch ON, See Figure 12 | 25°C | 2.7 V | 2.8 | | nA |
| $I_{COM(ON)}$ COM On leakage current | $V_{NC} \text{ or } V_{NO} = 2.3 \text{ V}$ or Open, $V_{COM} = 2.3 \text{ V}$ | Switch ON, See Figure 12 | 25°C | 2.7 V | 0.47 | | nA |
| DIGITAL INPUTS (IN) | | | | | | | |
| V_{IH} Input logic high | | | Full | | 1.8 | 5.5 | V |
| V_{IL} Input logic low | | | Full | | 0 | 0.6 | V |
| I_{IH}, I_{IL} Input leakage current | $V_{IN} = 5.5 \text{ V}$ or 0 | | Full | 2.7 V | -1 | 1 | μA |
| DYNAMIC | | | | | | | |
| t_{ON} Turn-on time | $V_{COM} = V_+$, $R_L = 50 \Omega$, | $C_L = 35 \text{ pF}$, See Figure 15 | 25°C Full | 2.3 V to 2.7 V | 40 | 55 70 | ns |
| t_{OFF} Turn-off time | $V_{COM} = V_+$, $R_L = 50 \Omega$, | $C_L = 35 \text{ pF}$, See Figure 15 | 25°C Full | 2.3 V to 2.7 V | 30 | 40 55 | ns |
| t_{BBM} Break-before-make time | $V_{NC} = V_{NO} = V_+ / 2$, $R_L = 50 \Omega$, | $C_L = 35 \text{ pF}$, See Figure 16 | 25°C Full | 2.3 V to 2.7 V | 1 | 33 39 | ns |
| Q_C Charge injection | $C_L = 1 \text{ nF}$, $V_{GEN} = 0 \text{ V}$, | See Figure 19 | 25°C | 2.5 V | 13 | | pC |
| $C_{NC(OFF)}, C_{NO(OFF)}$ NC, NO OFF capacitance | $V_{NC} \text{ or } V_{NO} = V_+ \text{ or GND}$, Switch OFF, | See Figure 14 | 25°C | 2.5 V | 23 | | pF |
| $C_{NC(ON)}, C_{NO(ON)}$ NC, NO ON capacitance | $V_{NC} \text{ or } V_{NO} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 2.5 V | 84 | | pF |
| $C_{COM(ON)}$ COM ON capacitance | $V_{COM} = V_+ \text{ or GND}$, Switch ON, | See Figure 14 | 25°C | 2.5 V | 84 | | pF |
| C_{IN} Digital input capacitance | $V_{IN} = V_+ \text{ or GND}$, | See Figure 14 | 25°C | 2.5 V | 2.1 | | pF |
| BW Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 16 | 25°C | 2.5 V | 100 | | MHz |
| O_{ISO} OFF isolation | $R_L = 50 \Omega$, $f = 1 \text{ MHz}$, | Switch OFF, See Figure 17 | 25°C | 2.5 V | -64 | | dB |
| X_{TALK} Crosstalk | $R_L = 50 \Omega$, $f = 1 \text{ MHz}$, | Switch ON, See Figure 18 | 25°C | 2.5 V | -64 | | dB |
| THD Total harmonic distortion | $R_L = 600 \Omega$, $C_L = 50 \text{ pF}$, | $f = 600 \text{ Hz to } 20 \text{ kHz}$, See Figure 19 | 25°C | 2.5 V | 0.025% | | |
| SUPPLY | | | | | | | |
| I_+ Positive supply current | $V_{IN} = V_+ \text{ or GND}$, | Switch ON or OFF | 25°C Full | 2.7 V | | 0.1 0.5 | μA |

(1) $T_A = 25^\circ\text{C}$

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6.8 Electrical Characteristics For 1.8-V Supply

$V_+ = 1.65\text{ V}$ to 1.95 V and $T_A = -40^\circ\text{C}$ to 125°C (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T_A | V_+ | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---|---|---|------------------------------|---------------------|----------------------------|------------|---------------|
| ANALOG SWITCH | | | | | | | |
| V_{COM}, V_{NO}, V_{NC} Analog signal range | | | | 0 | | V_+ | V |
| r_{peak} Peak ON-state resistance | $0 \leq V_{NO}$ or $V_{NC} \leq V_+$, $I_{COM} = -2\text{ mA}$ | Switch ON, See Figure 10 | 25°C Full | 1.8 V | 4 | 5.2 | Ω |
| r_{on} ON-state resistance | V_{NO} or $V_{NC} = 1.5\text{ V}$, $I_{COM} = -2\text{ mA}$ | Switch ON, See Figure 10 | 25°C Full | 1.8 V | 1.7 | 3.5 | Ω |
| Δr_{on} ON-state resistance match between channels | V_{NO} or $V_{NC} = 0.6\text{ V}, 1.5\text{ V}$, $I_{COM} = -2\text{ mA}$ | Switch ON, See Figure 10 | 25°C Full | 1.8 V | 0.7 | 0.7 | Ω |
| $r_{on(flat)}$ ON-state resistance flatness | $0 \leq V_{NO}$ or $V_{NC} \leq V_+$, $I_{COM} = -2\text{ mA}$ V_{NO} or $V_{NC} = 0.6\text{ V}, 1.5\text{ V}$, $I_{COM} = -2\text{ mA}$ | Switch ON, See Figure 11 | 25°C Full 25°C Full | 1.8 V | 1.85 1.85 0.9 0.9 | | Ω |
| $I_{NC(OFF)}, I_{NO(OFF)}$ NC, NO Off leakage current | V_{NC} or $V_{NO} = 1.65\text{ V}$, $V_{COM} = 0$ | Switch OFF, See Figure 11 | 25°C | 1.95 V | 0.2 | | nA |
| $I_{NC(ON)}, I_{NO(ON)}$ NC, NO On leakage current | V_{NC} or $V_{NO} = 1.65\text{ V}$, $V_{COM} = \text{Open}$ | Switch ON, See Figure 12 | 25°C | 1.95 V | 2.8 | | nA |
| $I_{COM(ON)}$ COM On leakage current | V_{NC} or $V_{NO} = 1.65\text{ V}$ or Open, $V_{COM} = 1.65\text{ V}$ | Switch ON, See Figure 12 | 25°C | 1.95 V | 0.47 | | nA |
| DIGITAL INPUTS (IN) | | | | | | | |
| V_{IH} Input logic high | | | Full | | 1.5 | 5.5 | V |
| V_{IL} Input logic low | | | Full | | 0 | 0.6 | V |
| I_{IH}, I_{IL} Input leakage current | $V_{IN} = 5.5\text{ V}$ or 0 | | Full | 1.95 V | -1 | 1 | μA |
| DYNAMIC | | | | | | | |
| t_{ON} Turn-on time | $V_{COM} = V_+$, $R_L = 50\ \Omega$ | $C_L = 35\text{ pF}$, See Figure 15 | 25°C Full | 1.65 V to 1.95 V | 65 | 70 95 | ns |
| t_{OFF} Turn-off time | $V_{COM} = V_+$, $R_L = 50\ \Omega$ | $C_L = 35\text{ pF}$, See Figure 15 | 25°C Full | 1.65 V to 1.95 V | 40 | 55 70 | ns |
| t_{BBM} Break-before-make time | $V_{NC} = V_{NO} = V_+ / 2$, $R_L = 50\ \Omega$ | $C_L = 35\text{ pF}$, See Figure 15 | 25°C Full | 1.65 V to 1.95 V | 1 0.5 | 60 72 | ns |
| Q_C Charge injection | $C_L = 1\text{ nF}$, $V_{GEN} = 0\text{ V}$ | See Figure 19 | 25°C | 1.8 V | 13 | | pC |
| $C_{NC(OFF)}, C_{NO(OFF)}$ NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_+$ or GND, Switch OFF | See Figure 14 | 25°C | 1.8 V | 23 | | pF |
| $C_{NC(ON)}, C_{NO(ON)}$ NC, NO ON capacitance | V_{NC} or $V_{NO} = V_+$ or GND, Switch ON | See Figure 14 | 25°C | 1.8 V | 84 | | pF |
| $C_{COM(ON)}$ COM ON capacitance | $V_{COM} = V_+$ or GND, Switch ON | See Figure 14 | 25°C | 1.8 V | 84 | | pF |
| C_{IN} Digital input capacitance | $V_{IN} = V_+$ or GND | See Figure 14 | 25°C | 1.8 V | 2.1 | | pF |
| BW Bandwidth | $R_L = 50\ \Omega$, Switch ON | See Figure 16 | 25°C | 1.8 V | 100 | | MHz |
| O_{ISO} OFF isolation | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$ | Switch OFF, See Figure 17 | 25°C | 1.8 V | -63 | | dB |
| X_{TALK} Crosstalk | $R_L = 50\ \Omega$, $f = 1\text{ MHz}$ | Switch ON, See Figure 18 | 25°C | 1.8 V | -63 | | dB |
| SUPPLY | | | | | | | |
| I_+ Positive supply current | $V_{IN} = V_+$ or GND | Switch ON or OFF | 25°C Full | 1.95 V | | 0.1 0.5 | μA |

(1) $T_A = 25^\circ\text{C}$

6.9 Typical Characteristics

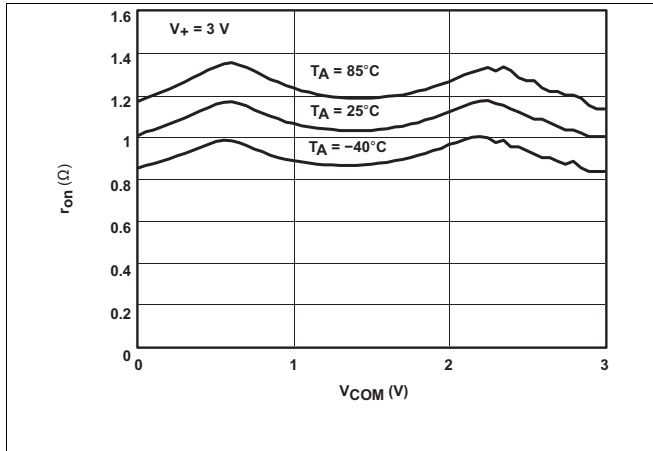


Figure 1. r_{on} vs V_{COM}

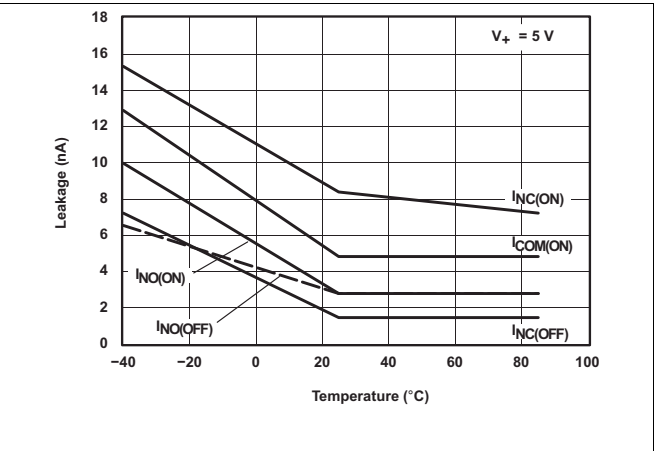


Figure 2. Leakage Current vs Temperature

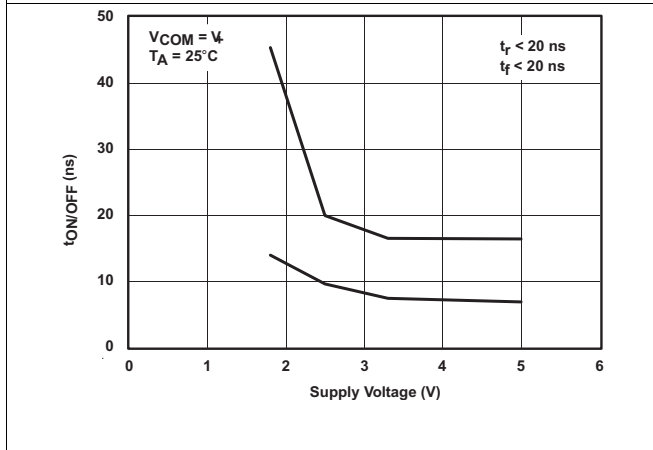


Figure 3. $t_{ON/OFF}$ vs V_+

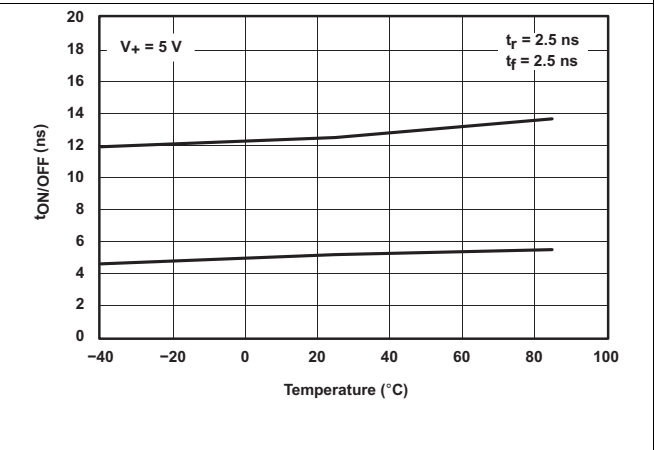


Figure 4. $t_{ON/OFF}$ vs Temperature

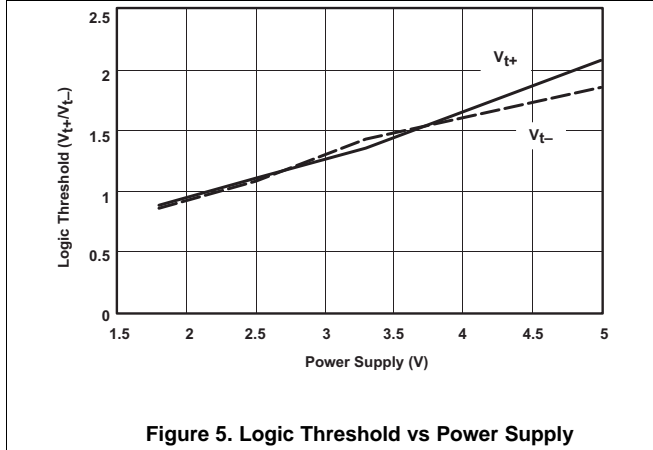


Figure 5. Logic Threshold vs Power Supply

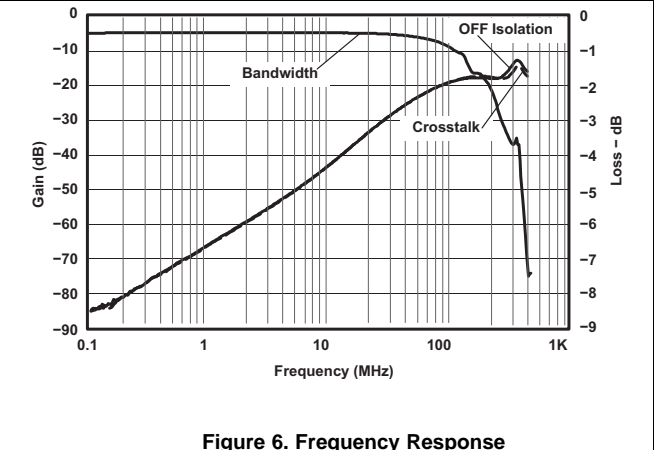


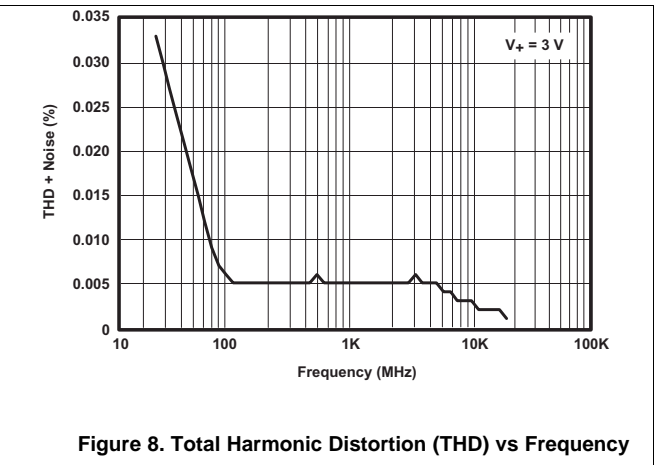
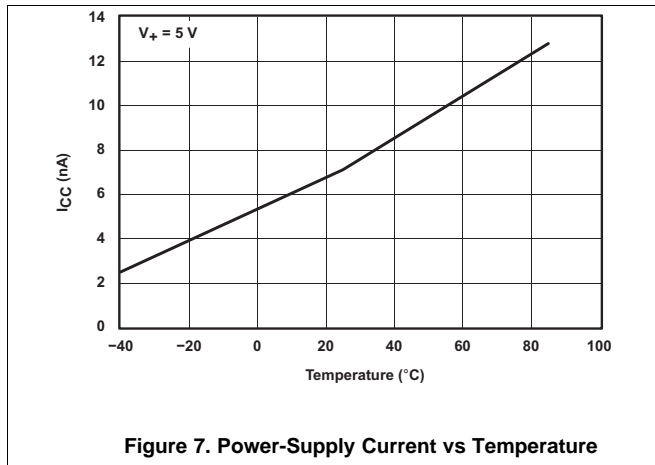
Figure 6. Frequency Response

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Typical Characteristics (continued)



7 Parameter Measurement Information

Table 1. Parameter Description

| SYMBOL | DESCRIPTION |
|------------------|--|
| V_{COM} | Voltage at COM |
| V_{NC} | Voltage at NC |
| V_{NO} | Voltage at NO |
| r_{on} | Resistance between COM and NC or COM and NO ports, when the channel is ON |
| r_{peak} | Peak ON-state resistance over a specified voltage range |
| Δr_{on} | Difference of r_{on} between channels |
| ron(flat) | Difference between the maximum and minimum value of r_{on} in a channel over the specified range of conditions |
| $I_{NC(OFF)}$ | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state under worst-case input and output conditions |
| $I_{NO(OFF)}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state under worst-case input and output conditions |
| $I_{NC(ON)}$ | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) being open |
| $I_{NO(ON)}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) being open |
| $I_{COM(ON)}$ | Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) being open |
| V_{IH} | Minimum input voltage for logic high for the control input (IN) |
| V_{IL} | Minimum input voltage for logic low for the control input (IN) |
| V_{IN} | Voltage at IN |
| I_{IH}, I_{IL} | Leakage current measured at IN |
| t_{ON} | Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM, NC, or NO) signal, when the switch is turning ON. |
| t_{OFF} | Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM, NC, or NO) signal, when the switch is turning OFF. |
| t_{BBM} | Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO), when the control signal changes state. |
| Q_C | Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC, NO, or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_O$, C_L is the load capacitance, and ΔV_O is the change in analog output voltage. |
| $C_{NC(OFF)}$ | Capacitance at the NC port when the corresponding channel (NC to COM) is OFF |
| $C_{NO(OFF)}$ | Capacitance at the NO port when the corresponding channel (NO to COM) is OFF |
| $C_{NC(ON)}$ | Capacitance at the NC port when the corresponding channel (NC to COM) is ON |
| $C_{NO(ON)}$ | Capacitance at the NO port when the corresponding channel (NO to COM) is ON |
| $C_{COM(ON)}$ | Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON |
| C_{IN} | Capacitance of IN |
| O_{ISO} | OFF isolation of the switch is a measurement OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state. |
| X_{TALK} | Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB. |
| BW | Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain. |
| I_+ | Static power-supply current with the control (IN) pin at V_+ or GND |
| ΔI_+ | This is the increase in I_+ for each control (IN) input that is at the specified voltage, rather than at V_+ or GND. |

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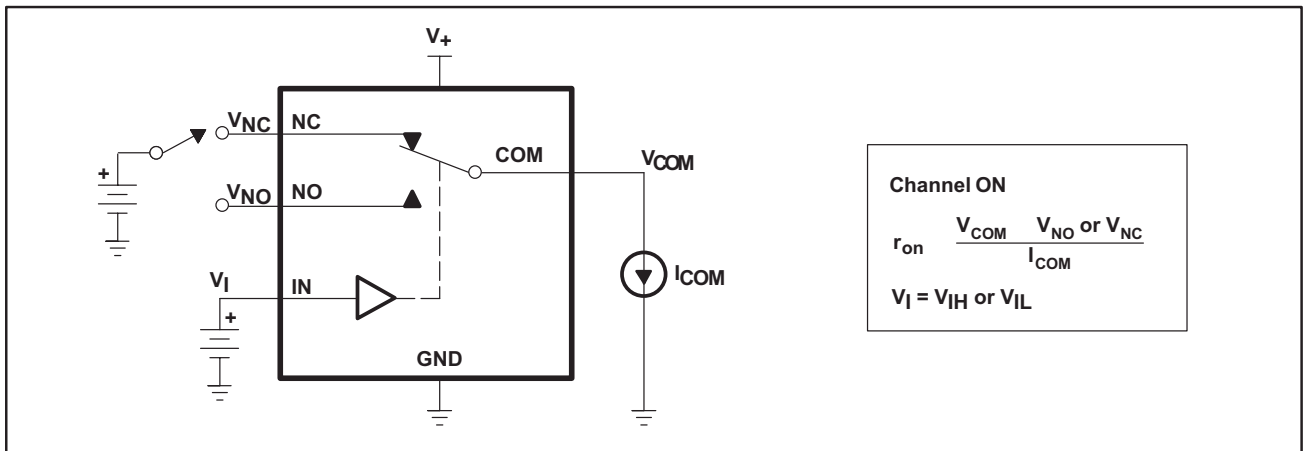


Figure 9. On-State Resistance (r_{on})

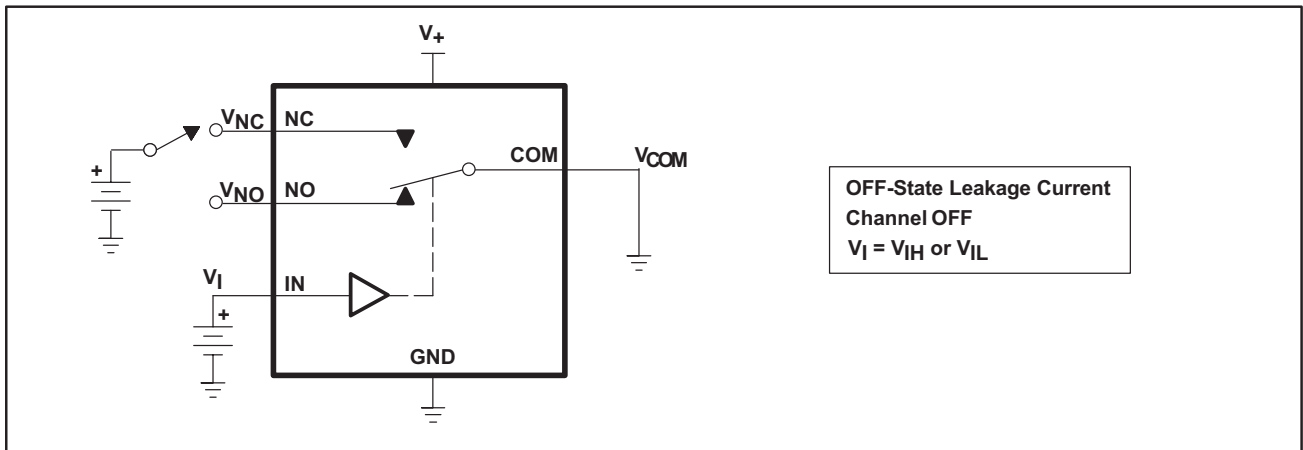


Figure 10. Off-State Leakage Current ($I_{NC(OFF)}$, $I_{NO(OFF)}$)

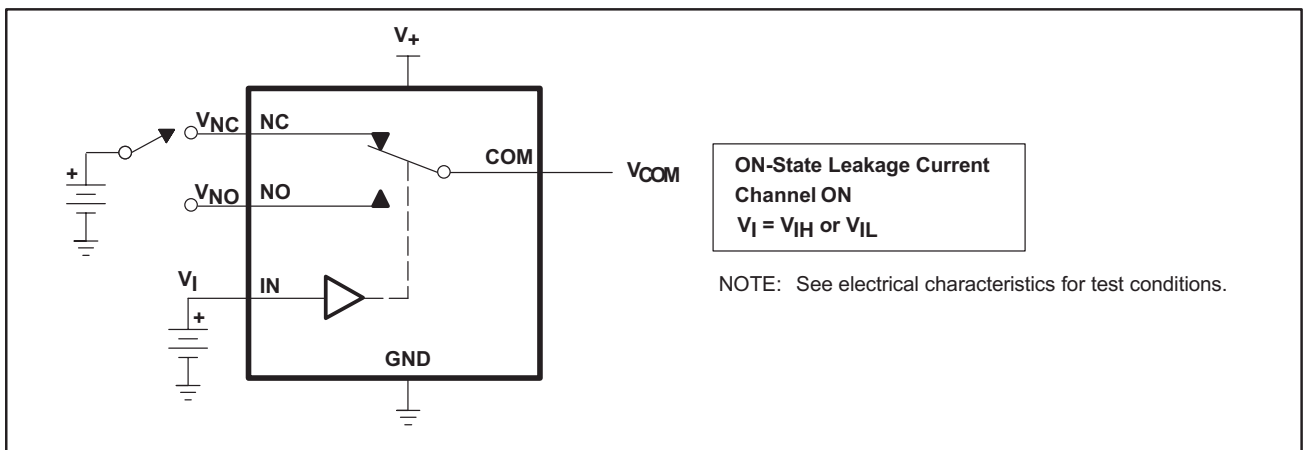


Figure 11. On-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$, $I_{NO(ON)}$)

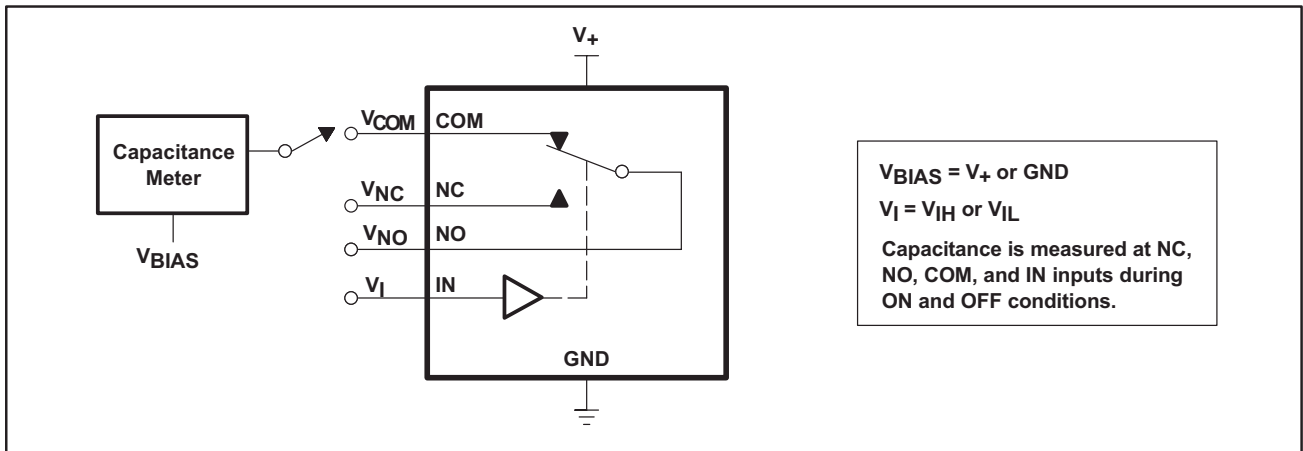
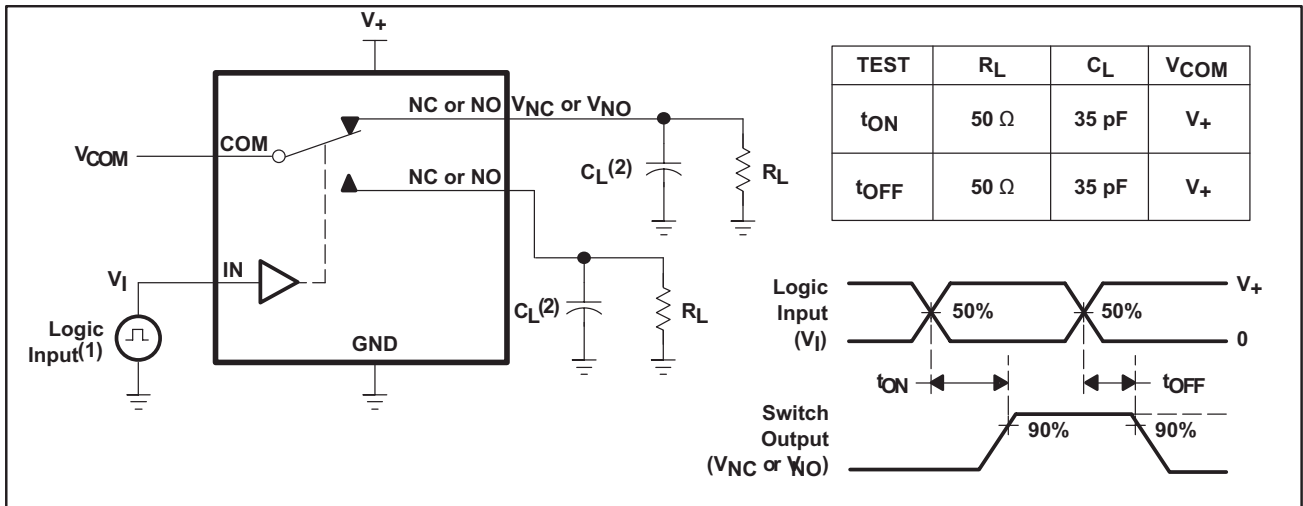


Figure 12. Capacitance (C_I , $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NO(OFF)}$, $C_{NC(ON)}$, $C_{NO(ON)}$)



(1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, ZO = 50 Ω, tr < 5 ns, tf < 5 ns.

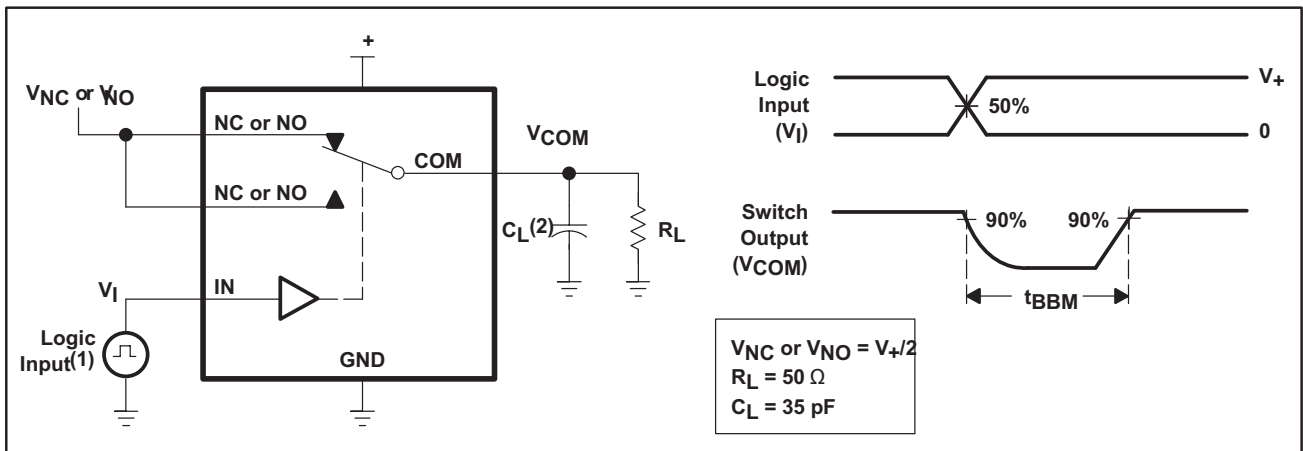
(2) CL includes probe and jig capacitance.

Figure 13. Turn-On (tON) and Turn-Off Time (tOFF)

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- (1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.
- (2) C_L includes probe and jig capacitance.

Figure 14. Break-Before-Make Time (t_{BBM})

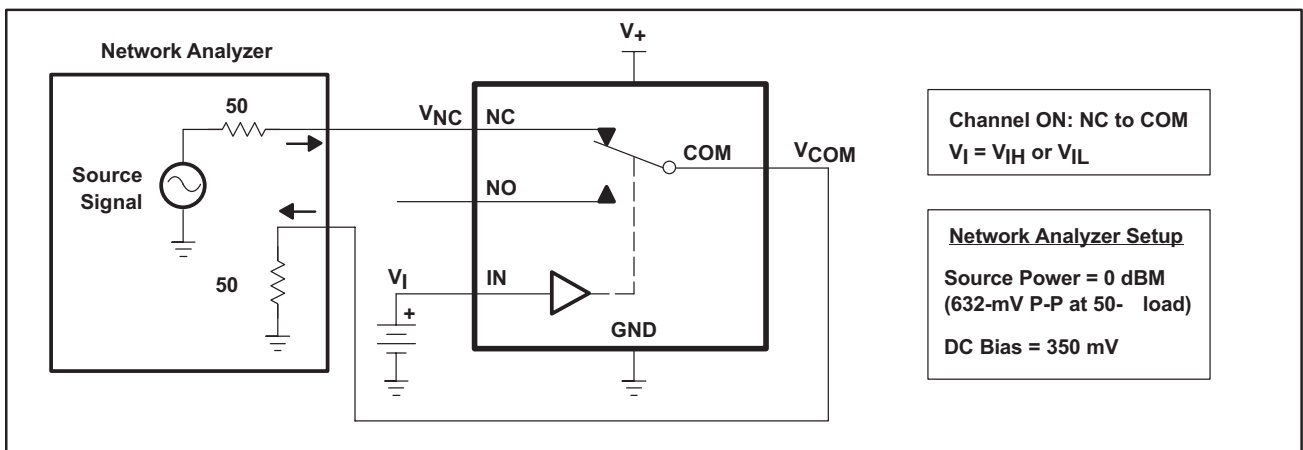


Figure 15. Bandwidth (BW)

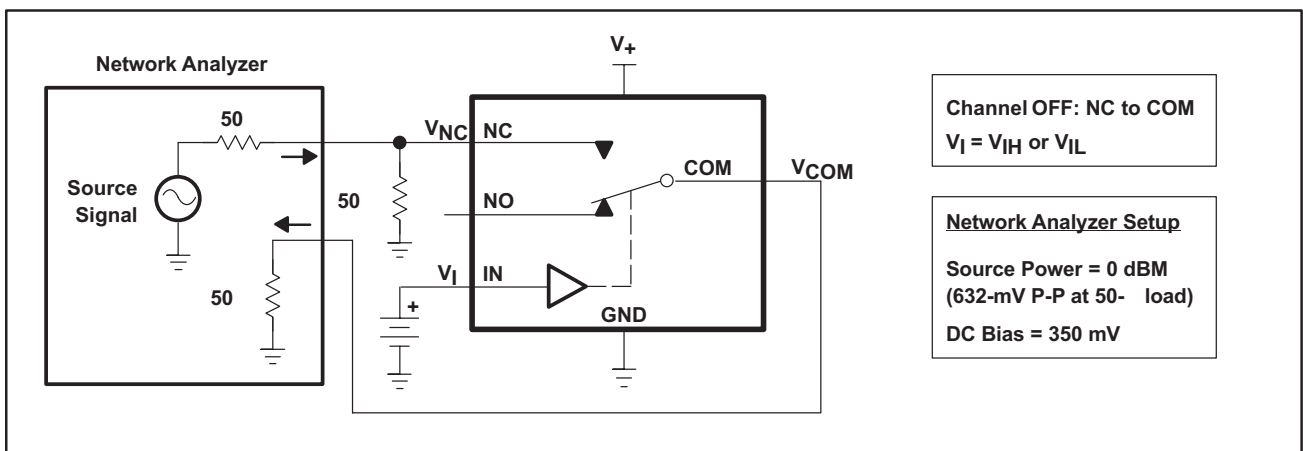


Figure 16. OFF Isolation (O_{ISO})

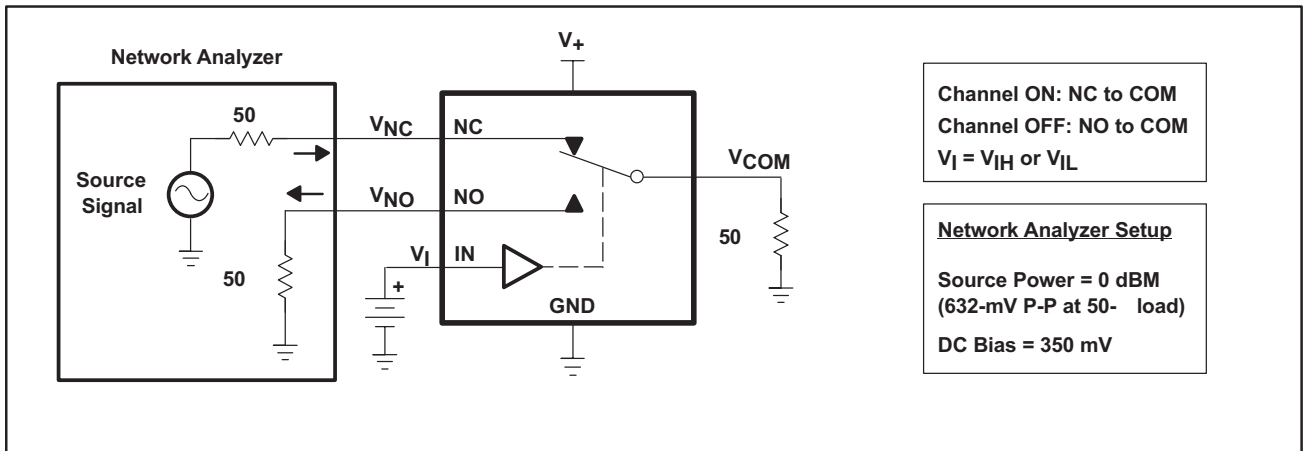
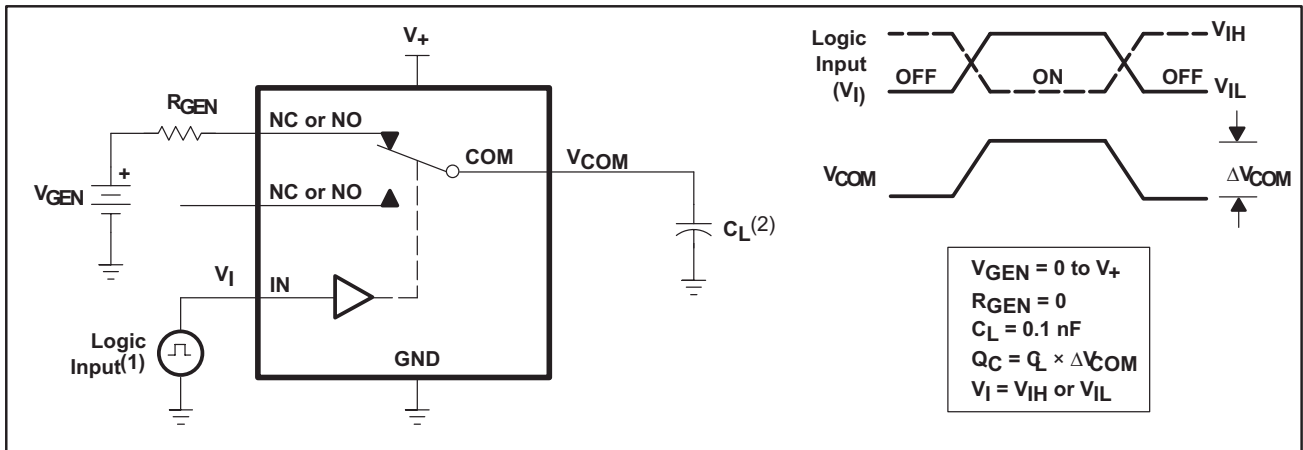


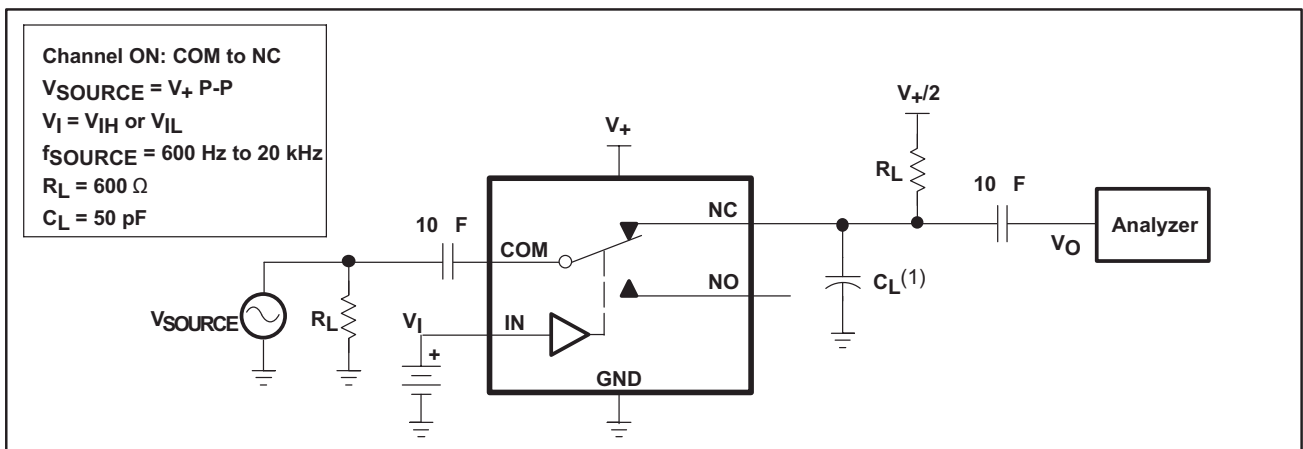
Figure 17. Crosstalk (X_{TALK})



(1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.

(2) C_L includes probe and jig capacitance.

Figure 18. Charge Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 19. Total Harmonic Distortion (THD)

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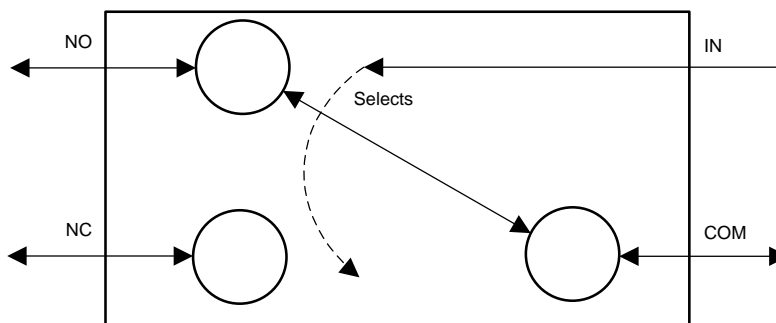
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8 Detailed Description

8.1 Overview

The TS5A3159-Q1 is a single-pole double-throw (SPDT) analog switch designed to operate from 1.65 V to 5.5 V. Either the NO or the NC pin is shorted to the COM pin, depending on the logic level input to the IN pin.

8.2 Functional Block Diagram



8.3 Feature Description

The main feature of this device is the excellent total harmonic distortion performance and low power consumption. Additionally, the NO, NC, and COM pins can be used as either inputs or outputs.

Table 2. Summary Of Characteristics⁽¹⁾

| CONFIGURATION | 2:1 MULTIPLEXER / DEMULTIPLEXER (1 × SPDT) |
|---|---|
| Number of channels | 1 |
| ON-state resistance (r_{on}) | 1.3 Ω |
| ON-state resistance match (Δr_{on}) | 0.1 Ω |
| ON-state resistance flatness ($r_{on(Flat)}$) | 0.15 Ω |
| Turn on/turn off time (t_{ON} / t_{OFF}) | 20 ns / 15 ns |
| Break-before-make time (t_{BBM}) | 12 ns |
| Charge injection (Q_C) | 36 pC |
| Bandwidth (BW) | 100 MHz |
| OFF isolation (O_{ISO}) | -65 dB at 1 MHz |
| Crosstalk (X_{TALK}) | -65 dB at 1 MHz |
| Total harmonic distortion (THD) | 0.01% |
| Leakage current ($I_{NO(OFF)} / I_{NC(OFF)}$) | ± 6 nA |
| Package option | 6-pin DBV |

(1) $V_+ = 5$ V and $T_A = 25^\circ\text{C}$

8.4 Device Functional Modes

Table 3 lists the functions for the TS5A3159-Q1 device.

Table 3. Function Table

| IN | NC TO COM, COM TO NC | NO TO COM, COM TO NO |
|----|----------------------|----------------------|
| L | ON | OFF |
| H | OFF | ON |

9 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

Analog switches are commonly used in battery powered applications to route audio signals. A typical use case is highlighted in Figure 20. The analog switch is supplied with 5 V and the control input is from a 5-V processor GPIO. In this case, there are no concerns related to excess power consumption.

9.2 Typical Application

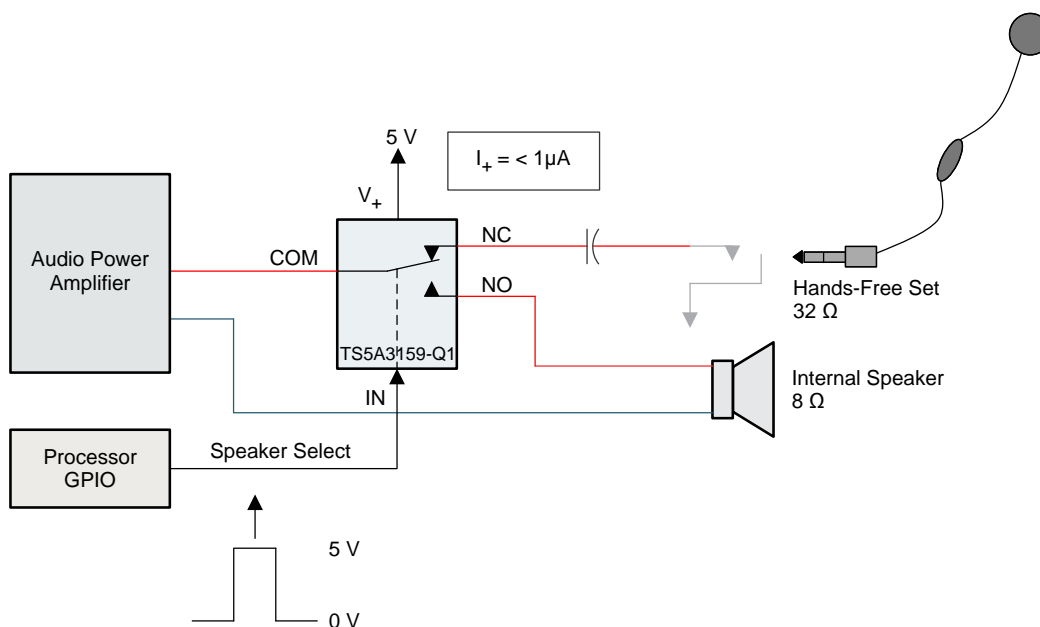


Figure 20. Typical Application Schematic

9.2.1 Design Requirements

In this application example, the device receives the control signal from a 5-V GPIO and common input from an Audio Power amplifier. The input is routed to either the Hands free set or the internal speaker depending upon the control signal.

9.2.2 Detailed Design Procedure

Since the control signal varies from 0 to 5 V (V_{dd}), there's no excess current consumption. However, if the control signal comes from lower voltage GPIOs while the V₊ of TS5A3159 is connected to the battery whose voltage varies, it can lead to an excess current draw from the V₊ suppl pin. Such a scenario requires the use of an external voltage level translator such as the SN74LVC1T45. For more information see *Preventing Excess Current Consumption on Analog Switches*, [SCDA011](#).

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Typical Application (continued)

9.2.3 Application Curve

The ON state resistance of the switch is a critical parameter to measure since it helps select the right switch for the application. The on state resistance versus the common voltage can be seen in Figure 21.

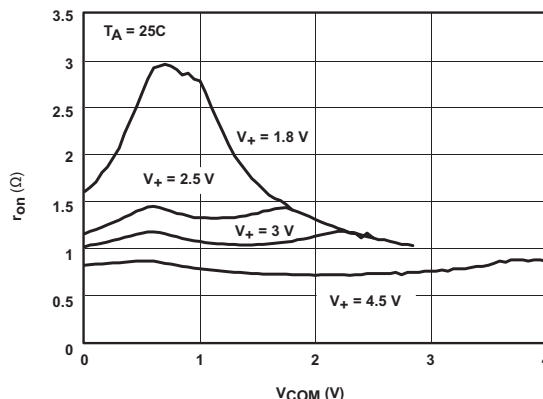


Figure 21. r_{on} vs V_{COM}

10 Power Supply Recommendations

Most systems have a common 3.3 V or 5 V rail that can supply the V+ pin of this device. If this is not available, a Switch-Mode-Power-Supply (SMPS) or a Linear Dropout Regulator (LDO) can supply this device from a higher voltage rail. Proper decoupling of the supply rail is a must to avoid any spikes that may exceed the absolute ratings of the V+ pin of the device.

11 Layout

11.1 Layout Guidelines

It is recommended to keep signal lines as short as possible. Incorporation of microstrip or stripline techniques is also recommended when signal lines are greater than 1 inch in length. These traces must be designed with a characteristic impedance of either 50 Ω or 75 Ω, as required by the application. Do not place this device too close to high voltage switching components, as they may cause interference.

11.2 Layout Example

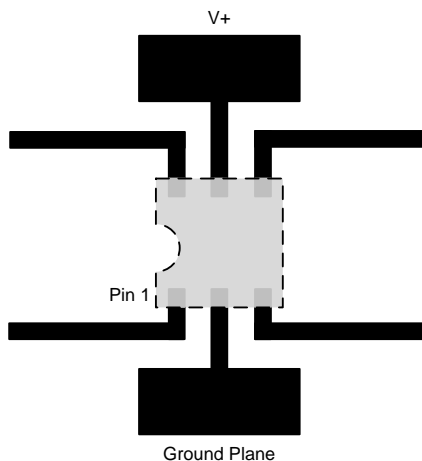


Figure 22. Layout Example

12 Device and Documentation Support

12.1 Documentation Support (if applicable)

12.1.1 Related Documentation

For related documentation see the following:

Preventing Excess Current Consumption on Analog Switches, [SCDA011](#)

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-------------------------|-------------------------|----------------------|--------------|-------------------------|---------|
| TS5A3159QDBVRQ1 | ACTIVE | SOT-23 | DBV | 6 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | | UAAQ | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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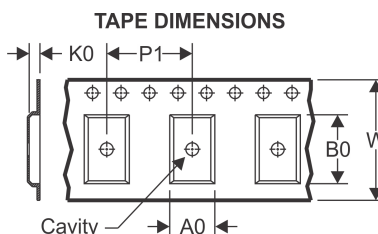
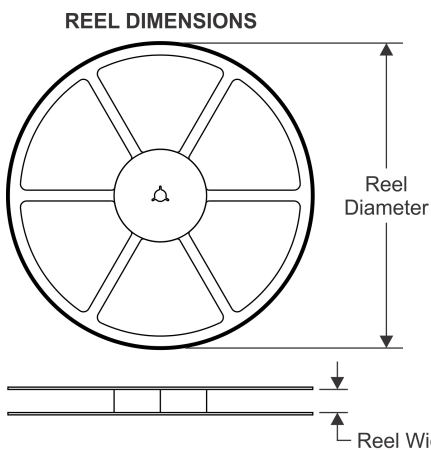
OTHER QUALIFIED VERSIONS OF TS5A3159-Q1 :

- Catalog: [TS5A3159](#)
- Enhanced Product: [TS5A3159-EP](#)

NOTE: Qualified Version Definitions:

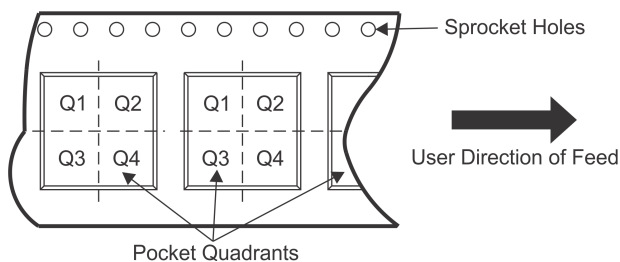
- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

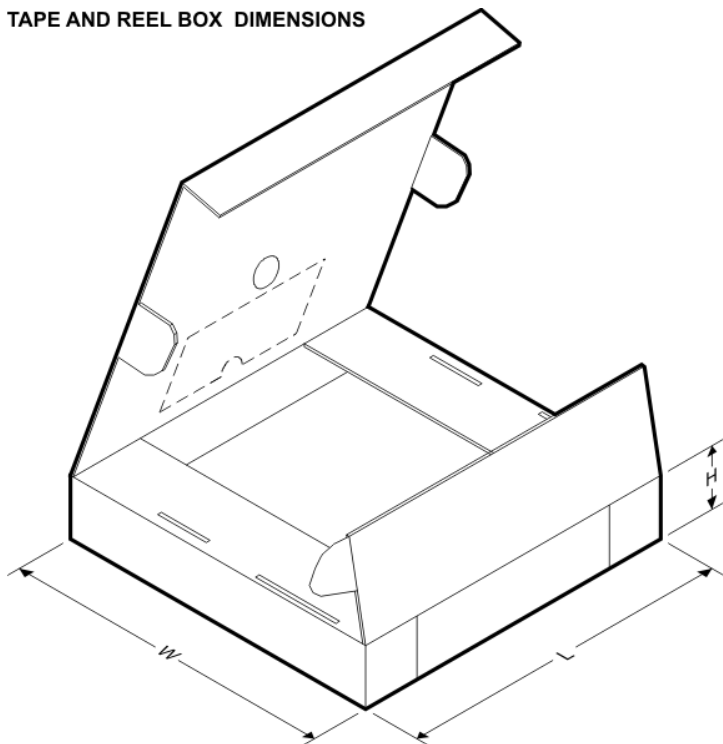
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TS5A3159QDBVRQ1 | SOT-23 | DBV | 6 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |

TAPE AND REEL BOX DIMENSIONS



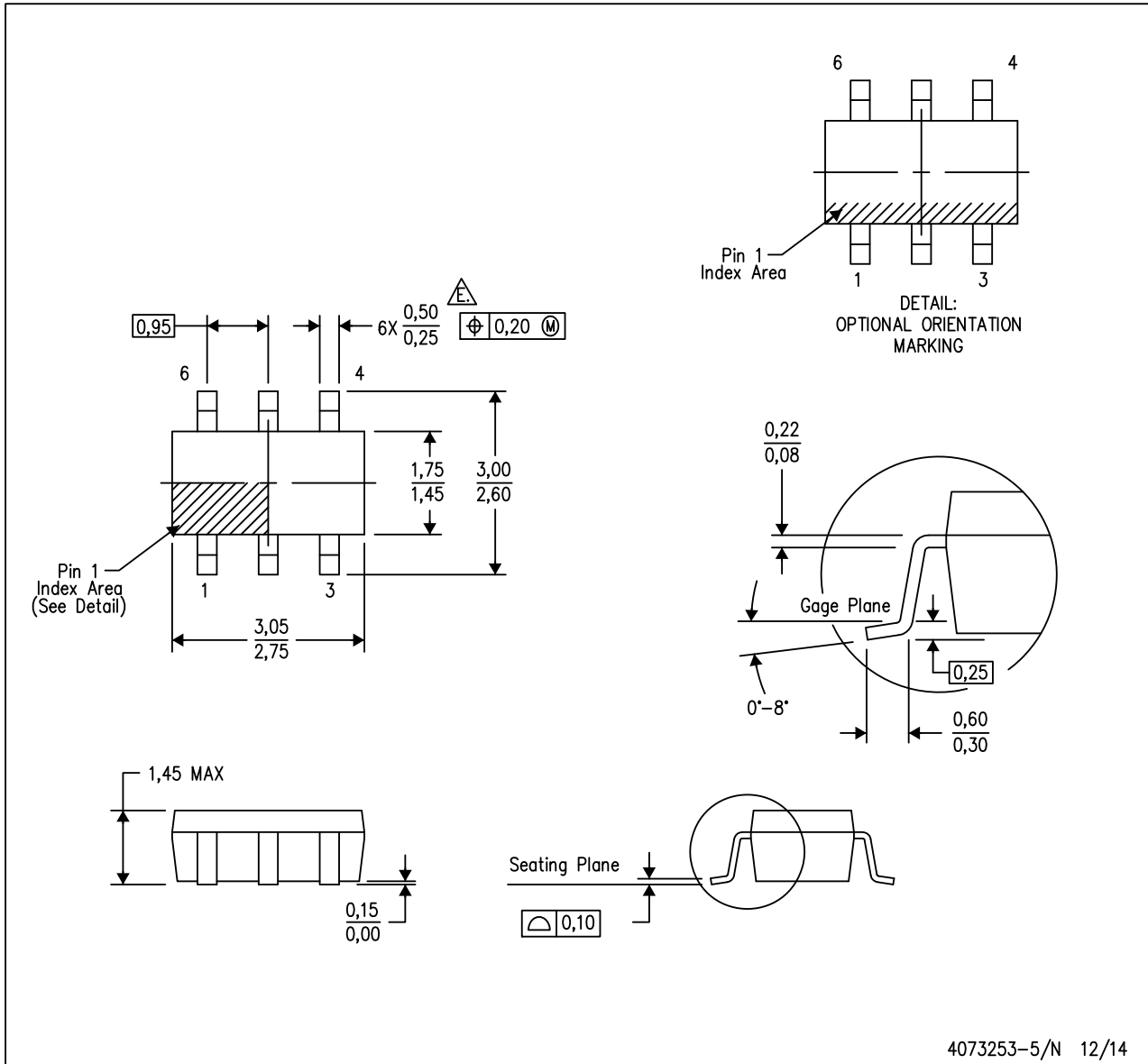
*All dimensions are nominal


| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TS5A3159QDBVRQ1 | SOT-23 | DBV | 6 | 3000 | 202.0 | 201.0 | 28.0 |

MECHANICAL DATA

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE

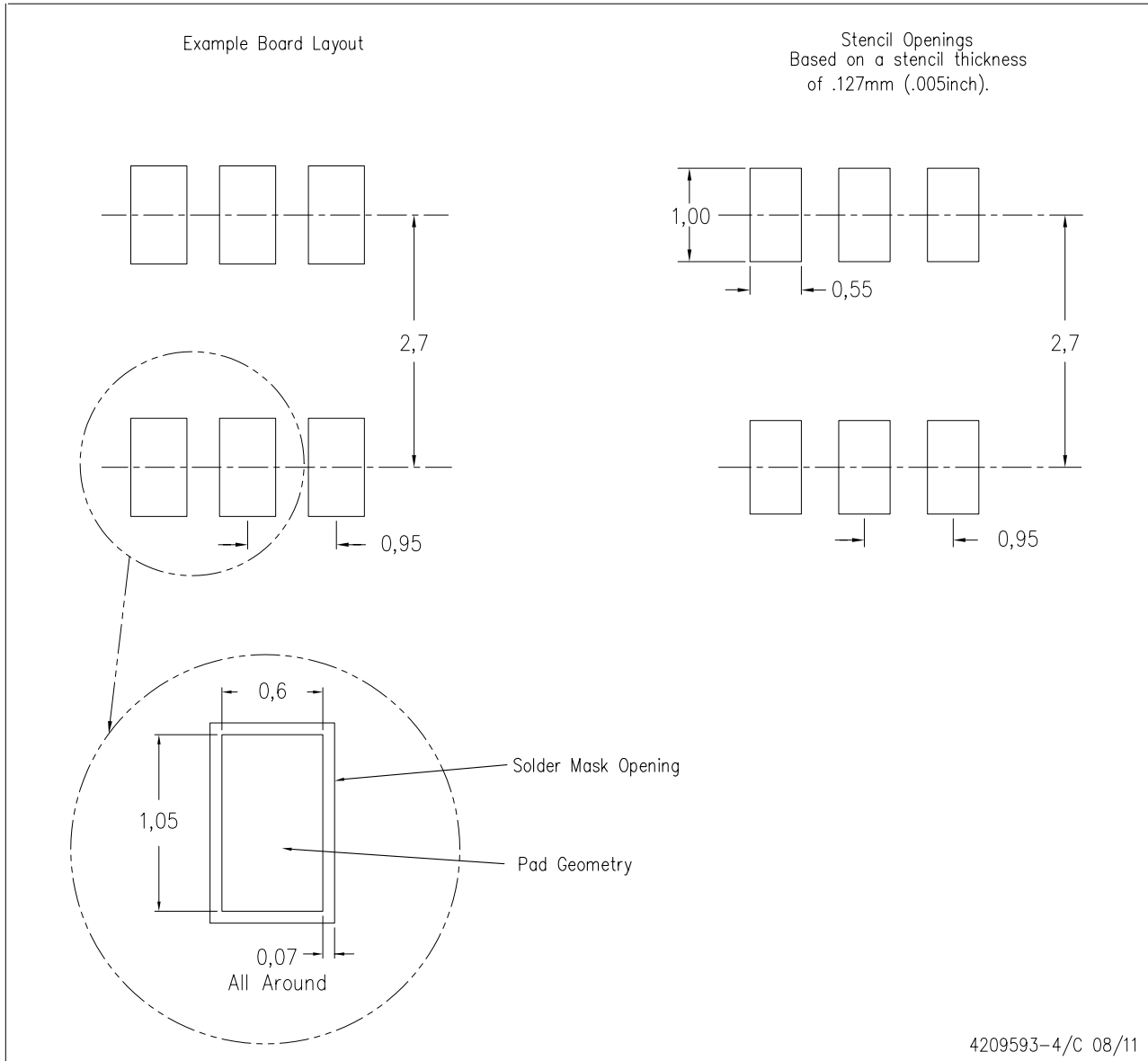


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
-  Falls within JEDEC MO-178 Variation AB, except minimum lead width.

LAND PATTERN DATA

DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE

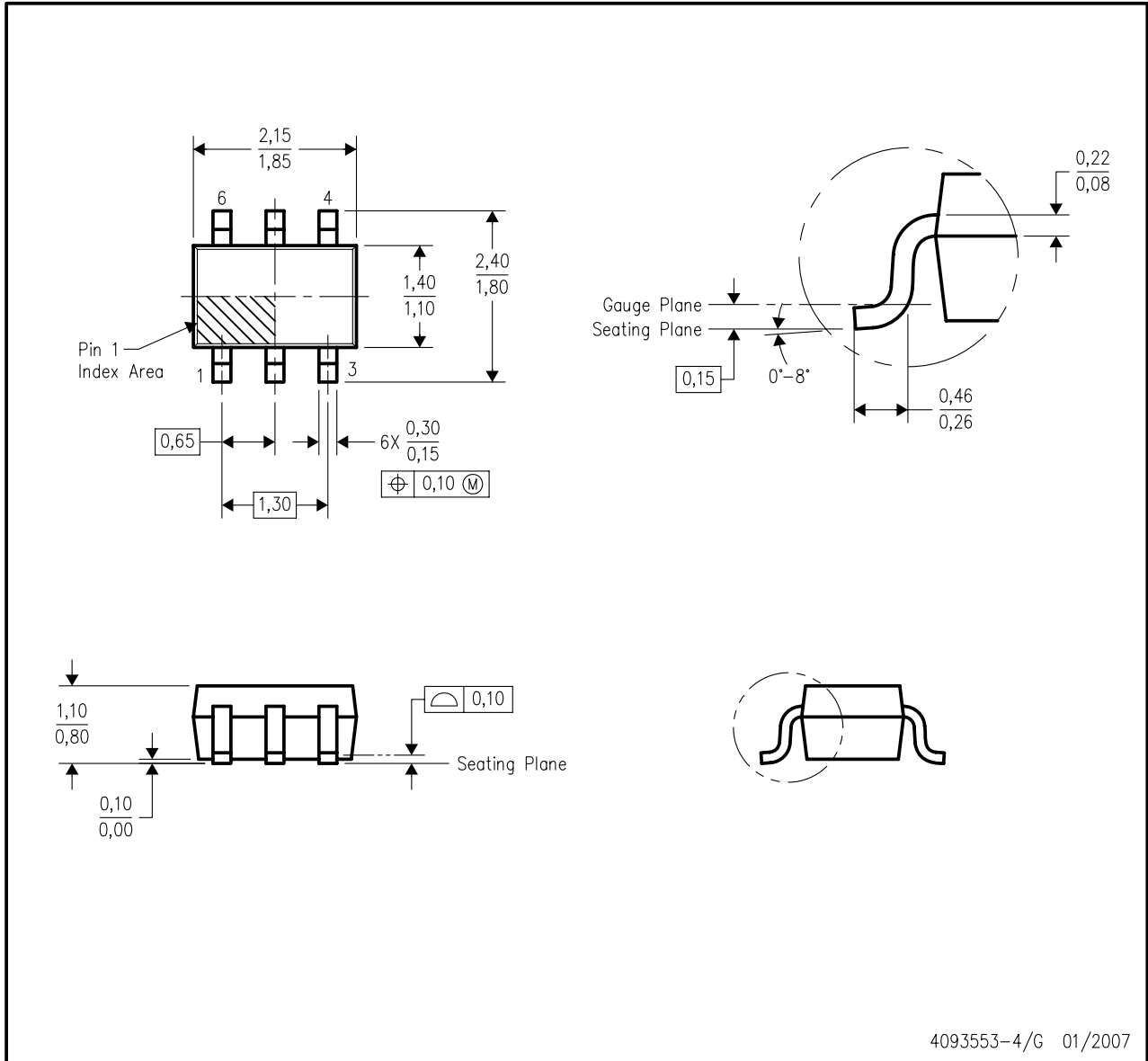


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

MECHANICAL DATA

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.

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